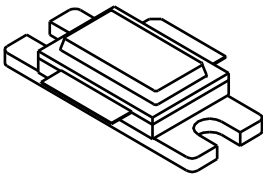




MDS500L
500 Watts, 50 Volts, Pulsed
Avionics 1030 MHz

PRELIMINARY

<p>GENERAL DESCRIPTION</p> <p>The MDS500L is a high power COMMON BASE bipolar transistor. It is designed for MODE-S ELM systems in the 1030 MHz frequency band. The transistor includes input prematch for broadband performance. The device has gold thin-film metallization and diffused ballasting in a hermetically sealed package for proven highest MTTF.</p>	<p style="text-align: center;">CASE OUTLINE 55ST Style 1</p> 
<p>ABSOLUTE MAXIMUM RATINGS</p> <p>Maximum Power Dissipation Device Dissipation @25 C¹ 833 W</p> <p>Maximum Voltage and Current Collector to Emitter Voltage (BV_{ces}) 70 V Emitter to Base Voltage (BV_{ebo}) 3.5 V Peak Collector Current (I_c) 25 A</p> <p>Maximum Temperatures Storage Temperature -65 to +150 C Operating Junction Temperature +200 C</p>	

ELECTRICAL CHARACTERISTICS @ 25 C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
P _{out}	Power Out	F = 1030 MHz	500			W
P _{in}	Power Input	V _{cc} = 50 Volts			70	W
P _g	Power Gain	PW = Note 2 DF = Note 2	8.5			dB
η _c	Collector Efficiency			50		%
V _{SWR}	Load Mismatch Tolerance	F = 1030 MHz			3:1	
Pd ¹	Pulse Droop	F = 1030 MHz			0.8	dB
Trise ¹	Rise Time				100	nSec

FUNCTIONAL CHARACTERISTICS @ 25 C

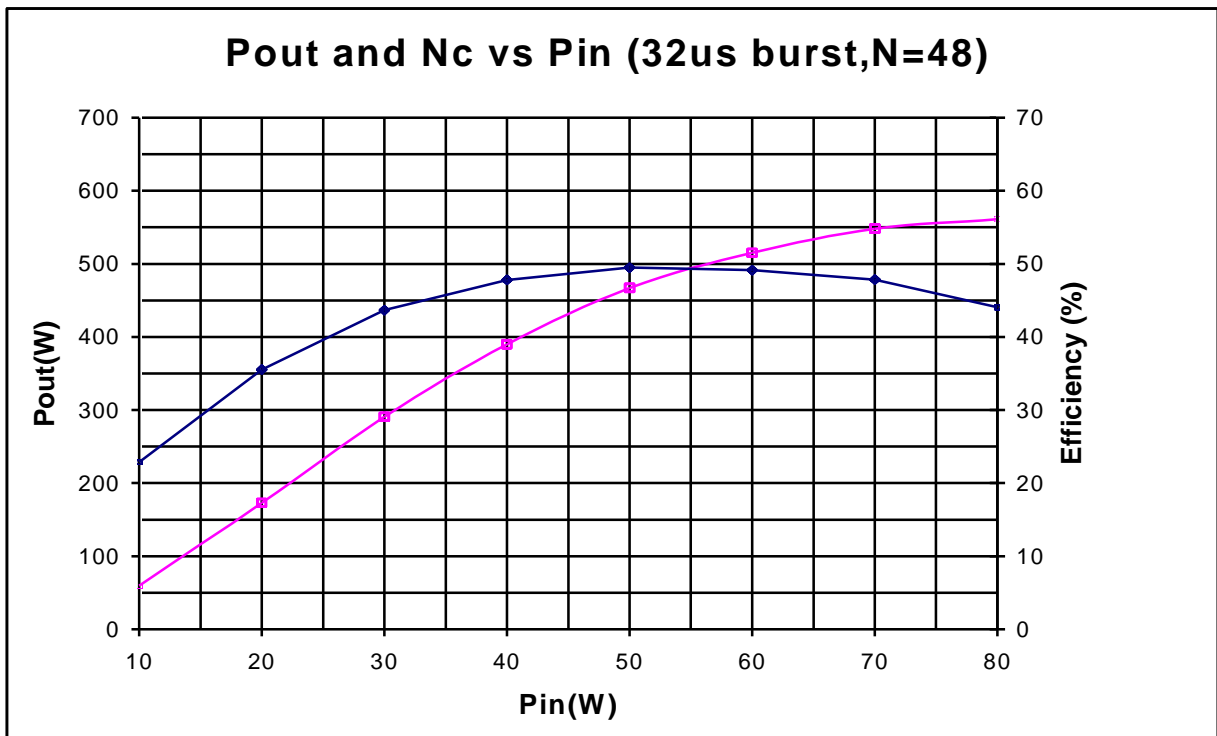
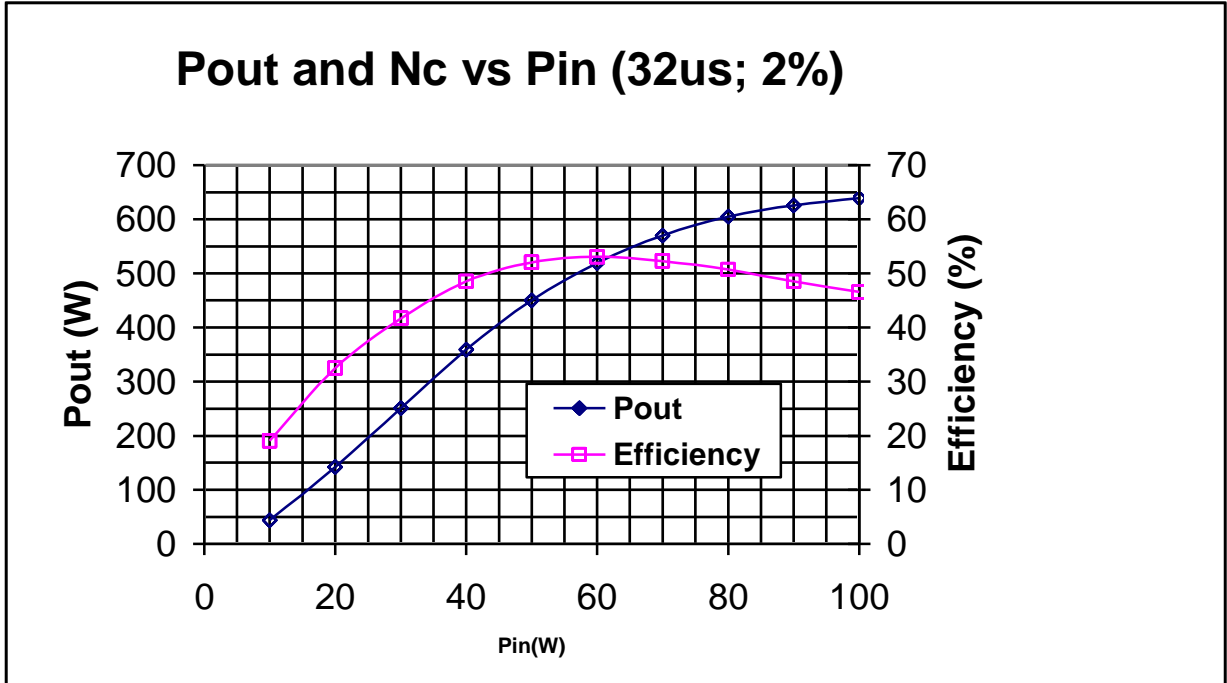
BV _{ebo}	Emitter to Base Breakdown	I _e = 30 mA	3.0			V
BV _{ces}	Collector to Emitter Breakdown	I _c = 50 mA	70			V
BV _{cbo}	Collector to Base Breakdown	I _c = 50 mA	70			V
I _{ces}	Collector to Emitter Leakage	V _{ce} = 50V			15	mA
h _{FE}	DC – Current Gain	V _{ce} = 5V, I _c = 1.0 A	20			
jc ¹	Thermal Resistance				0.21	C/W

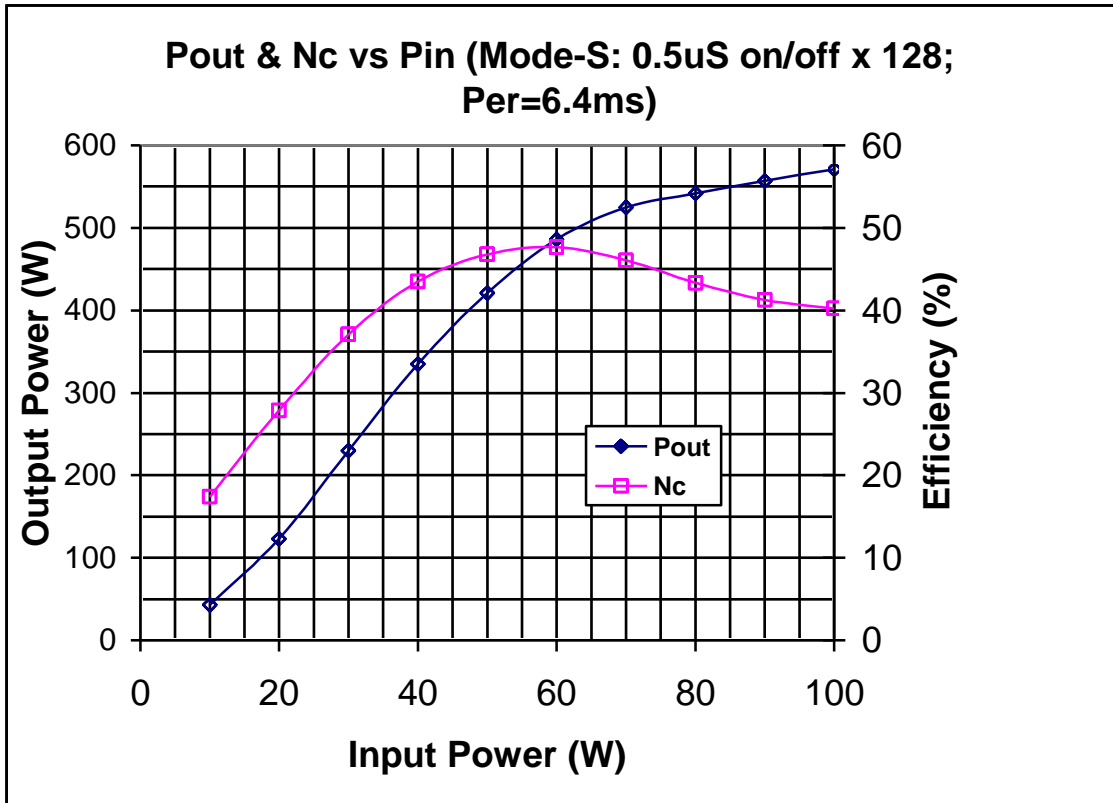
NOTE 1: AT RATED OUTPUT POWER AND PULSE CONDITIONS

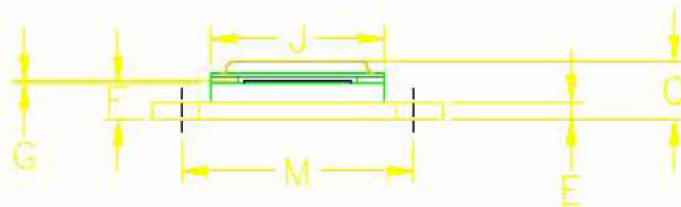
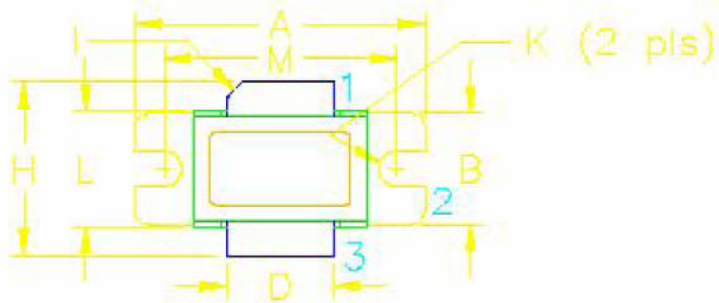
NOTE 2: Burst: 32μSec ON/ 18μSec OFF x 48, repeated at 23mSec

Rev. A May 2006

Microsemi reserves the right to change, without notice, the specifications and information contained herein. Visit our web site at www.microsemi.com or contact our factory direct.



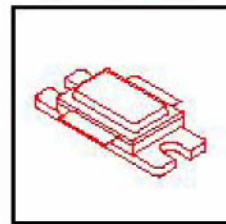




DIM	MILLIMETER	±TOL	INCHES	±TOL
A	25.40	.25	1.000	.010
B	9.78	.25	.385	.010
C	4.00	.19	.142	.007
D	9.40	.13	.370	.005
E	1.53	.13	.060	.005
F	3.18	.13	.125	.005
G	0.08	+0/-0	.003	+0.02/-0
H	19.05	0.51	.750	.020
I	45°	5°	45°	5°
J	15.24	.25	.600	.010
K	3.05 DIA	.13	.120 DIA	.005
L	10.15	.13	.400	.005
M	20.32	.25	.800	.010

STYLE 1:
 PIN 1 = COLLECTOR
 2 = BASE
 3 = EMITTER

STYLE 2:
 PIN 1 = COLLECTOR
 2 = EMITTER
 3 = BASE



DWC NO.

55ST